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Pseudo-Capacitance of Silver Oxide Thin Film Electrodes in Ionic Liquid for Electrochemical Energy Application

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Abstract

The energy storage potential of silver oxide (Ag_2O) thin film electrodes, deposited via radio frequency reactive magnetron sputtering, were investigated in an ionic electrolyte (1-Ethyl-3-methylimidazolium bis(trifluoromethylsulfonyl)imide for supercapacitor application. X-ray diffraction (XRD), Raman spectroscopy, X-ray photoelectron spectroscopy (XPS) and Fourier Transform infrared spectroscopy (FTIR) tools were used to evaluate the structural and oxide phases present in the sputtered silver oxide thin film electrodes. The growth mode, morphology, surface area, wettability and surface energy of the deposited nano-structure silver oxide thin films were confirmed with scanning electron microscope (SEM), Brunauer-Emmett-Teller (BET), goniometer and tensiometer. Furthermore, ion diffusion, Faradaic redox reactions and capacitance of the sputtered thin films exposed to 1-Ethyl-3-methylimidazolium bis(trifluoromethylsulfonyl)imide ionic electrolyte, were monitored with electrochemical impedance spectroscopy (EIS) and cyclic voltammetry (CV). SEM micrograph depicts that silver oxide thin films exhibit columnar growth mode, with wettability analysis revealing that Ag_2O thin film is hydrophilic, an excellent electrochemical behaviour indicator. Cyclic voltammetry measurements show that Ag_2O thin films exhibit a specific capacitance of 650 F/g at higher sputtering power, demonstrating its promising potential as an active electrode for supercapacitor application.

Keywords: Silver oxide, BET, EIS, cyclic voltammetry, pseudocapacitor

1. Introduction

The population of the world is expected to be on the increase as the years go by, therefore the use of energy is expected to increase with population density [1]. The fuel cell and battery technologies have been excellent storage systems for decades, however, the primary concern with them is that they are not suitable for burst power applications, due to their low power density output [2-4]. Storage devices like supercapacitors with their enormous power density and excellent cycle life are designed and engineered to solve the present and future energy storage problem [3-4]. The energy storage mechanism in supercapacitor could either be via charge separation in the Helmholtz double layer or reverse faradaic redox (oxidation-reduction) reaction on the electrode surface [5-6]. Supercapacitor performance depends on the kind of electroactive material used for the fabrication of the electrodes. This impacts the level of capacitive performance, energy density and power density of the supercapacitor [7]. The active electrode materials used for supercapacitor processing are grouped into carbon, conducting polymers and transition metal oxide-based materials, with carbon-based materials predominantly used for processing EDLC type of supercapacitors. The conducting polymers and transition metal oxide materials are mainly used for the pseudocapacitor kind of supercapacitor, while the combination of the three materials is for processing the composite electrodes for hybrid supercapacitors. Activated carbon is one the most investigated carbon materials for EDLC because of their low cost, high surface area and good electrical properties, but yields lower energy density and are unsuitable for high-temperature use [8]. Transition metal oxide-based electrodes such as ruthenium oxide (RuO_2) [9-10], manganese oxide (MnO_2) [11], vanadium oxide (V_2O_5) [12], Iron oxide (Fe_2O_3) [13], solves the problem that carbon base materials are faced by [8]. Despite ruthenium oxide excellent electrochemical performance, its toxicity to the environment and its high cost hinders its wider commercialization as electroactive material for supercapacitor applications. Investigating alternative base material such as silver oxide that is cheap and has the potential to exhibits electrochemical behaviour close to that of ruthenium oxide is the aim of this research. Silver forms different oxide phases such as AgO , Ag_3O_4 , Ag_4O_3 , Ag_2O_3 and Ag_2O with silver oxide (Ag_2O) been the most stable amongst them [14]. The ability for silver oxide to change and adopt different oxidation states (+1, +2), facilitates the energy storage ability of Ag_2O . Silver oxide has previously been studied by various researchers for different applications such as anti-microbial agent [15-17], due to the release of silver ion (Ag^+), reactive oxygen species (ROS) and the hydroxyl group, which are produced from redox

reaction. Fuji et al. [18] and Kim et al. [19] reported silver oxide widely used in optical disk storage due to their photoactivation properties. Her et al. [20] integrated silver oxide thin films into super resolution near field structures, for optical memory applications. Silver oxides nanostructured particles have also served as a protective coating material, to stop the degradation of zinc oxide-based photodetectors [21]. Silver oxide thin film coating has been deployed successfully as a substrate for surface-enhanced Raman spectroscopy for molecular level detection [22]. Silver oxide nanomaterials have been studied and found to be highly conductive, making them suitable for battery cell applications [23-25]. Porous morphology, good conductivity, good thermal stability and reasonable wettability are some of the characteristics [23-29], attributed to silver oxide, making it a promising electroactive material for pseudocapacitor applications. In this work, the energy storage potential of Ag₂O thin films produced by reactive magnetron sputtering was investigated in ionic electrolyte to determine its electrochemical performance and suitability for supercapacitor application.

2. Experimental Investigation

The thin film disposition parameters, structural characterization and electrochemical measurement details are described by Oje et al. [28]. The charge-discharge measurement was carried out for 10000 cycles for an applied current and voltage window of 10mA and 1V respectively. Furthermore, the following voltage range was used for the cyclic voltammetry analysis -1000mV to 1000mV, for scan rate of 2mV/s, 5mV/s and 10mV/s respectively.

3. Results and Discussion

3.1 XRD, Raman, FTIR and XPS results

The diffraction peaks for the crystal structure of Ag₂O thin films sputtered on microscope glass slides, were established using the standard international centre for diffraction data card number (ICCD CARD number: 041-1104). The Bragg peaks on the Ag₂O thin films deposited at 250W, 300W, 350W and at oxygen flow rates of 10sccm reveal that the deposited silver oxide thin films are crystalline as shown in Figure 1a, with peaks at (111), (002) and (200) crystal planes, reflecting silver oxide cubic structure. The sharp Bragg peak on the (200) crystal planes of Ag₂O 350W 10sccm thin film, Reddy et al. [30] and Hammad et al. [31], attribute to increase in crystal grain size as deposition power increases. The crystal grain orientation of the silver oxide changes from (111) to (200) crystal plane, an indication that the sputtered silver oxide thin film is nonhomogeneous [29, 31-33]. This also suggests that the non-uniformity of the sputtered Ag₂O thin films increase with deposition power.

Furthermore, Ingham et al. [34], reported that the shift in the 2θ angles of the crystal planes of silver oxide in Figure 1a is due to the sputtered Ag_2O thin films nonhomogeneous and columnar growth structure. The packing arrangement in the cubic structure of silver oxide deposited at all the conditions are in cubic shape at the (111), (002) and (200) crystal planes [29,32,35,36-38]. This gives rise to the cubic interstitial site, where electrolyte diffusion can take place, thereby encouraging redox reaction process.

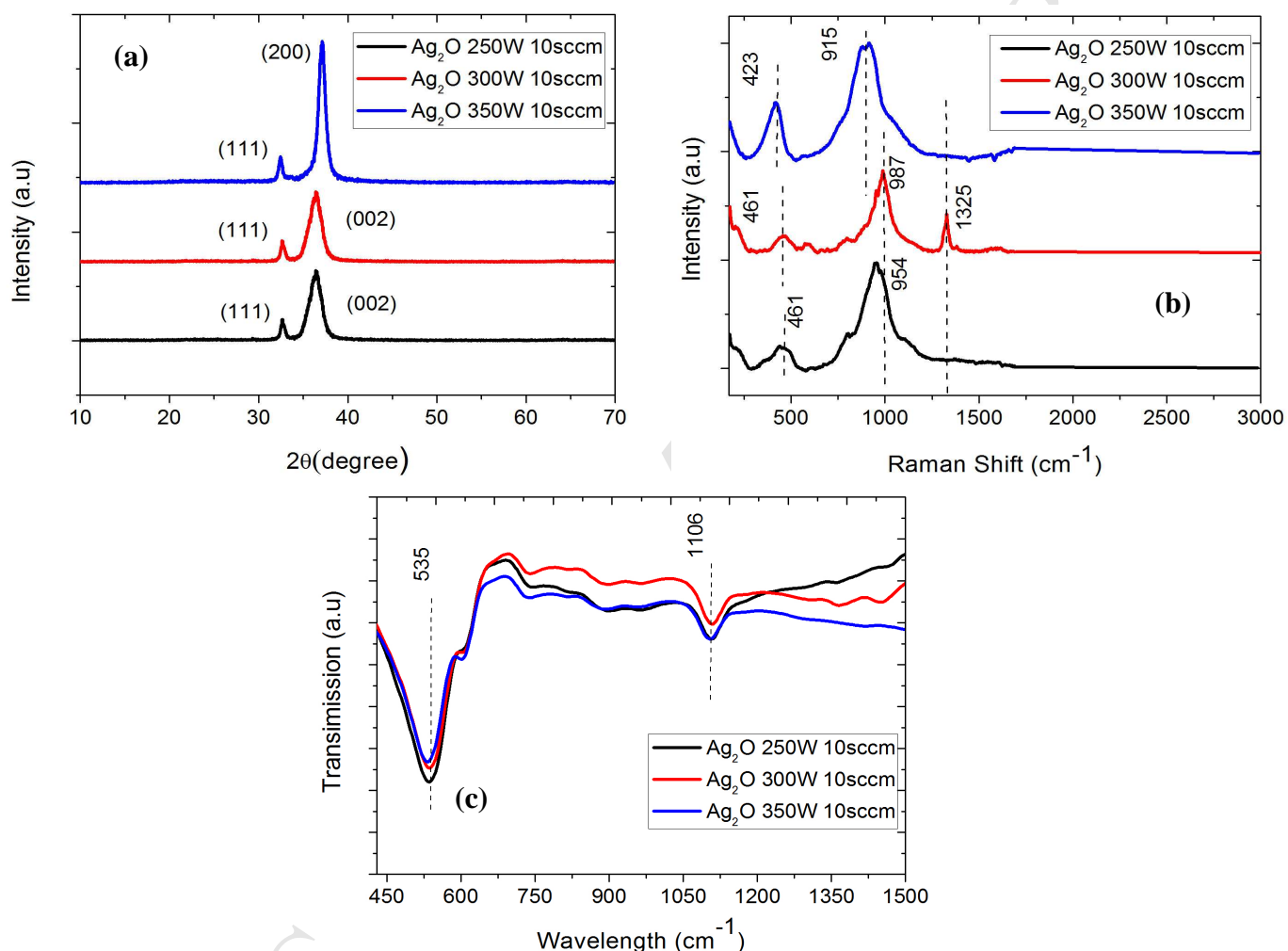


Figure 1: (a) XRD (b) Raman and (c) FTIR results of Ag_2O thin films deposited at 250W, 300W and 350W at oxygen flow rate of 10sccm

The Raman spectroscopy of Ag_2O thin films shown in Figure 1b (250W, 300W and 350W) for oxygen flow rate of 10sccm exhibits Raman bands at 423 cm^{-1} , 461 cm^{-1} , 915 cm^{-1} , 954 cm^{-1} , 987 cm^{-1} and 1325 cm^{-1} . The Raman shift at 423 cm^{-1} and 461 cm^{-1} are due to the stretching mode of silver oxide on the (111) crystal lattice, where the oxygen molecules

occupy the cubic interstitial holes [34,39-40]. There is a shift in the Raman peaks as the deposition power increases for silver oxide thin films produced at radio frequency power of 250W, 300W and 350W at 10sccm oxygen flow rate. This is due to the ability of the grain boundaries trapping more oxygen molecules at higher deposition power for the silver oxide thin film deposited at 350W 10sccm. Martina et al. [41], attribute the 915 cm^{-1} , 954 cm^{-1} and 987 cm^{-1} Raman spectra peaks to chemisorbed atomic/molecular oxygen species end bond on deposited Ag_2O thin films with (002) and (200) crystal lattices being the preferred cubic interstitial sites for the oxygen molecules. Furthermore, the 1325 cm^{-1} peaks are the sums of the Ag-O (270 cm^{-1}) and O-O (930 cm^{-1}) stretching mode, giving rise to superimposed vibrational mode.

Figure 1c shows the deposited silver oxide thin films FTIR spectra, with peaks at 535 cm^{-1} and 1106 cm^{-1} . The 535 cm^{-1} peak is the lattice vibration mode of silver oxide, due to the Ag-O-Ag bonding and the 1106 cm^{-1} is attributed to O-H stretching vibration mode. This vibration lattice peak is within the FTIR vibrational mode reported in various literature reviews on silver oxide FTIR spectrum [42-45]. There is a continuous increase in the FTIR peak intensity as the deposition power increases for Ag_2O thin films prepared at (250W, 300W and 350W) as shown in Figure 1c. This is due to the ability of sputtering gases to acquire more excitation energy at higher power and dislodge more silver atoms from the target, thereby increasing the deposition rate, the films thickness and crystal size of the deposited Ag_2O thin films as forward power increases. Silver oxide vibrational lattice peak at 535 cm^{-1} arises from the (002) and (200) crystal planes. The cubic interstitial site on the crystal planes provides spaces for the diffused oxygen molecules to bond with the silver atoms. This bonding at this cubic interstitial site leads to Ag-O-Ag vibrational lattice and the eventual FTIR silver oxide peak at 535 cm^{-1} . At higher deposition power, more intense silver oxide films are produced and this confirms the XRD and Raman spectroscopy findings.

XPS was used to study the elemental constituent of the prepared silver oxide thin films and other elements they are bonded to. The binding energy of 368.3eV and 531.8 eV in Figure 2a, Figure 2b indicate the presence of Ag (Ag 3d) and oxygen (O 1s) [36,46-48] in the sputtered sample. The bonding of Ag-O in the deposited thin film sample is evidenced in the O1s spectra, at 531.8 eV binding energy [36,49-52], which stems from subsurface oxygen formation. The survey spectrum in Figure 2c reveals the presence of silver metal and atomic oxygen at a binding energy of 390 eV and 560 eV. Kaspar et al. [46], reported similar binding

energy for metallic silver co-deposited with atomic oxygen. The XPS binding energies at 368.3eV and 531.8 eV are within the standard values for silver and oxygen atoms.

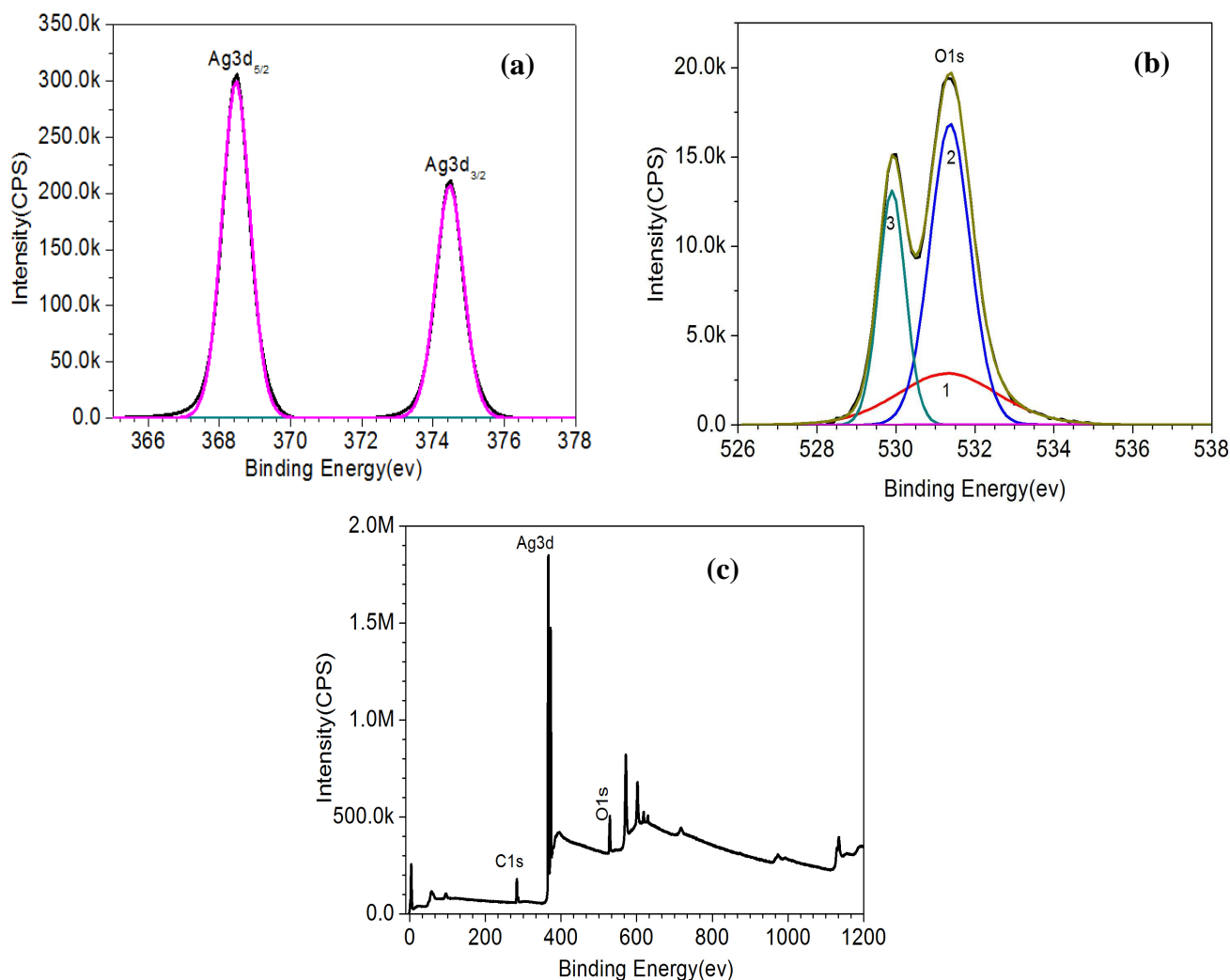


Figure 2: XPS of silver oxide (a) Ag 3d (b) O1s and (c) survey spectrum

3.2 SEM Results and BET Surface Area.

A scanning electron microscope (SEM) was deployed to reveal the microstructural information of the produced Ag₂O thin film electrodes. The top surface view of the Ag₂O thin films SEM micrograph in Figure 3a, Figure 3b and Figure 3c, reveal agglomeration of silver oxide crystals as shown on films prepared at 250W. As deposition power increased, Volmer-Weber growth mode mechanism (island growth mode) can be seen on the top view micrographs of the sputtered Ag₂O thin films, similar to Rebelo [36] findings. The prepared silver oxide thin films crystal size increases with sputtering power, which Agasti et al. [52] attribute to the trapping of more atoms of oxygen inside the grain boundaries as deposition power increases. The prepared Ag₂O thin film electrodes at oxygen flow rate of 10sccm and

sputtering power (250W, 300W and 350W) exhibited columnar growth mode from the cross-sectional view in Figure 3. The columnar growth structure, island formation and segregation of silver and oxygen atoms lead to void creations. This island growth exhibited by silver oxide thin films, allow the molecules to be bonded strongly to each other, enabling the clustering of the atoms. As the deposition power increases, the pores on the silver oxide thin films become more pronounced, and atoms agglomerate forming a larger island. Rebelo et al. [36], believes this is due to the growth of stable nuclei to the maximum and the ability of more oxygen molecules to diffuse at higher deposition power. The improved roughness and mesopores as deposition power increases, enhance conductivity, improves ion diffusion and facilitates the redox reaction [31, 53-59]. This is an indication that Ag_2O 350W 10sccm will offer more surface area for electrode/electrolyte interaction, resulting in higher specific capacitance.

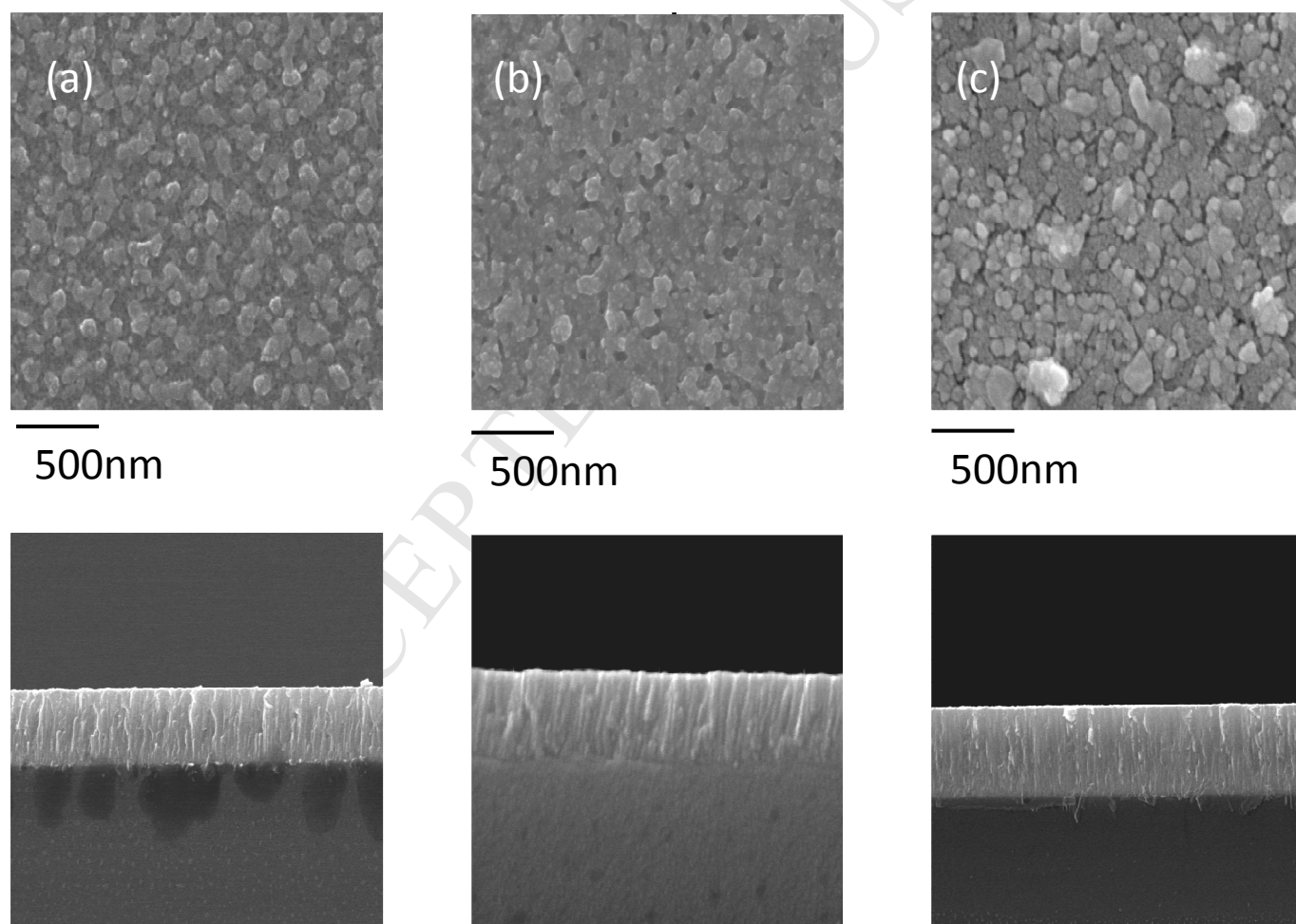


Figure 3: SEM images of silver oxide thin films deposited at 10sccm showing top and cross-sectional view (a) 250W (b) 300W and (c) 350W

BET analysis was used to evaluate the surface area and the average pore size of the deposited silver oxide thin films and the results presented in Table 1. The BET experimental analysis reveals that the surface area and average pore size of the sputtered Ag₂O thin films, increases as deposition power increases as depicted in Table 1. Dimitrijević et al. [60] and Agasti et al. [61], attributes this to ions been more energetic as sputtering power increases from 250W to 350W, resulting in bigger surface area and more probability of nanoclusters. Arjomandi et al. [62] suggest that higher surface area allows faster transport through the electrolyte ions and this increases the supercapacitor performance [63], supporting SEM results. Furthermore, Zhao et al. [64], reported that electrode surface area and pore size are directly connected to specific capacitance, with more surface area presenting more active sites for interfacial faradaic reaction and charge storage. An indication that energy density can be improved by increasing specific capacitance, a direct impact of surface area and pore size improvement.

Table 1: BET surface area and average pore size of silver oxide thin films

Deposition Power (W)	BET surface area (m ² /g)	Pore Size (nm)
250	26.19	9.41
300	38.21	12.49
350	41.04	15.03

3.3 Wettability and Surface Energy Analysis

Figure 4 shows the wettability analysis of the Ag₂O thin film electrodes conducted using contact angle measurement. The results of Ag₂O thin films static and dynamic plot show that silver oxide is hydrophilic, with all the contact angle less than 90°, signifying good wettability as shown in Figure 4. Figure 4a shows a continuous decrease in the static contact angle of Ag₂O thin films as deposition power increases. An indication that silver oxide electrode/electrolyte interaction improves as sputtering power increases. Figure 4b reveals similar results for contact angle measurement using dynamic techniques, further confirming the hydrophilic nature of the deposited thin films. The advancing and the receding contact angle differences give rise to contact angle hysteresis, due to the change in the surface configuration (SEM) of the sputtered Ag₂O thin films [65-68]. This is an indication of electrolyte intrusion into the silver oxide thin films mesopores. Ag₂O 350W 10sccm sputtered

thin film electrode yields smaller contact angle hysteresis in contrast to the Ag_2O thin films prepared at 250W and 300W respectively. An indication of Ag_2O 350W 10sccm higher degree of wetting and diffusion of the electrolyte into the microstructure of the electrode [65-67]. Wettability and electrolyte penetration lead to improved charge transfer process across the electrode-electrolyte, thereby encouraging the pseudocapacitance process. The cubic interstitial sites [68], provide the sites for electrolyte penetration and diffusion for the electrochemical performance of the deposited thin films. SEM micrograph and wettability results of silver oxide thin films suggest that Ag_2O 350W 10sccm is the most viable electrode material for pseudocapacitor application.

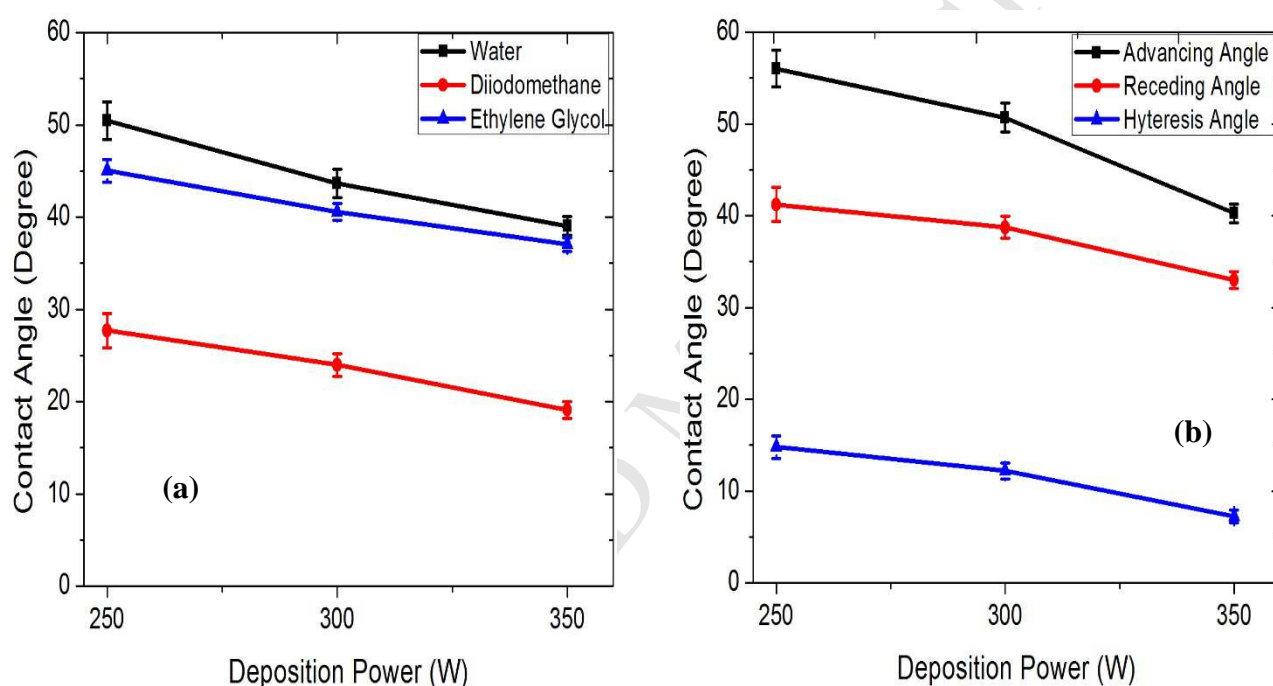


Figure 4: Contact angle graphs of Ag_2O thin films (a) static, (b) dynamic

Surface energy analysis was performed using three approaches namely: Fowkes, Wu and acid-base approach. Figure 5 and Table 2 reveal that, the total surface energy (γ^{total}) of the Ag_2O thin films increased as deposition power increases [29]. The wettability of the deposited Ag_2O thin films depends on the overall contribution of the polar component γ^{p} to the entire surface energy. The higher the polar component contribution to the overall surface energy, the better the wettability of the films [69] as shown in Figure 5a, 5b and Table 2. Silver oxide thin film sputtered at 350W, show higher polar component contribution to the

total surface energy. This is an indication of its excellent electrode/electrolyte interaction resulting in lower contact angle, supporting the contact angle results. The sputtered Ag₂O 350W 10sccm excellent wettability is evident in the magnitude of the polar components in the Fowkes, Wu and acid-base surface energy depicted in Figure 5a, 5b and Table 2.

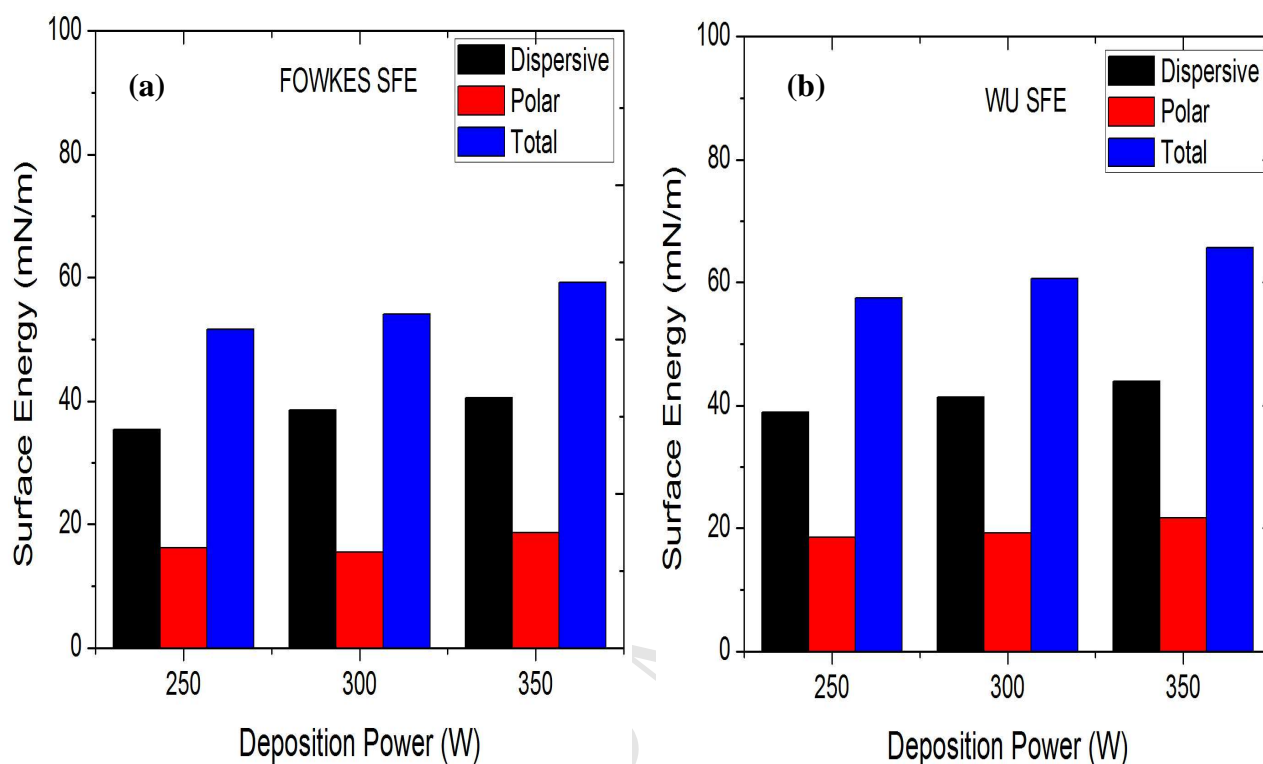


Figure 5: Ag₂O thin films Surface Energy using (a) Fowkes and (b) Wu approach

Table 2: silver oxide thin films surface energy

Power (W)	Surface Energy (mN/m)								
	Fowkes			Wu			Acid-Base		
	γ^d	γ^p	γ^{total}	γ^d	γ^p	γ^{total}	γ^{lw}	γ^{AB}	γ^{total}
250	35.43	15.14	50.57	38.86	18.57	57.43	46.94	-6.04	40.90
300	38.56	15.56	54.12	41.38	19.24	60.62	49.08	-4.10	44.98
350	40.51	18.67	59.18	43.98	21.64	65.62	50.80	-2.18	48.62

3.4 Electrochemical Impedance Spectroscopy (EIS)

Figure 6 shows the Electrochemical Impedance Spectroscopy results of Ag_2O thin films in an ionic electrolyte, presented using Nyquist and Bode plot. The sputtered Ag_2O thin film electrode at 350W 10sccm displays Warburg diffusion line 45° to the Z-axis, an ion intercalation process, which reveals the pseudocapacitive characteristics of the Ag_2O thin films produced at 350W 10sccm [70-73]. The electron charge transfer process a second part of the ion intercalation, reveals lower impedance value for Ag_2O 350W 10sccm, making it the most conductive silver oxide prepared for this investigation. This can be linked to the Ag_2O 350W 10sccm sample offering more surface area and more pore size for ion diffusion, which improves the electrochemical performance. There is a shift in Ag_2O 250W 10sccm and Ag_2O 300W 10sccm electrodes, from the 45° spectra line to the Z axis as shown in Figure 6a. These variations, Criado et al. [74] linked to non-uniformity of Ag_2O thin films coating and the reflective boundary condition at the electrode. The Bode plot in Figure 6b further supports the Nyquist plot finding, with Ag_2O 350W 10sccm thin film again exhibiting lower impedance compared to 250W 10sccm and 300W 10sccm electrodes. The equivalent circuit model of the various sputtered Ag_2O thin film electrodes was simulated using a Z-view software. Silver oxide thin films prepared at 250W 10sccm, 300W 10sccm and 350W 10sccm correspond to charge transfer resistance of 32.09Ω , 28.72Ω and 22.14Ω respectively. The reduced charge transfer resistance offered by silver oxide thin film processed at 350W 10sccm indicate better ionic electrolyte transport via the electrolyte/electrode interface. Pawar et al. [75], reported that the lower impedance of silver oxide thin film sputtered at 350W 10sccm (22.14Ω) is an indication of its high conductivity and the ability to offer more surface area for ion diffusion for better electrochemical supercapacitor performance [76]. The wettability analysis further explains this, where Ag_2O 350W 10sccm showed the lowest contact angle, due to the dominant contribution from the polar component of the total surface energy. This suggests that the surface of the Ag_2O thin film deposited at 350W 10sccm had maximum interaction with the three probing liquids, used during the contact angle analysis. This leads to lower contact angle and higher surface energy values as depicted in Figure 4 and Figure 5 respectively.

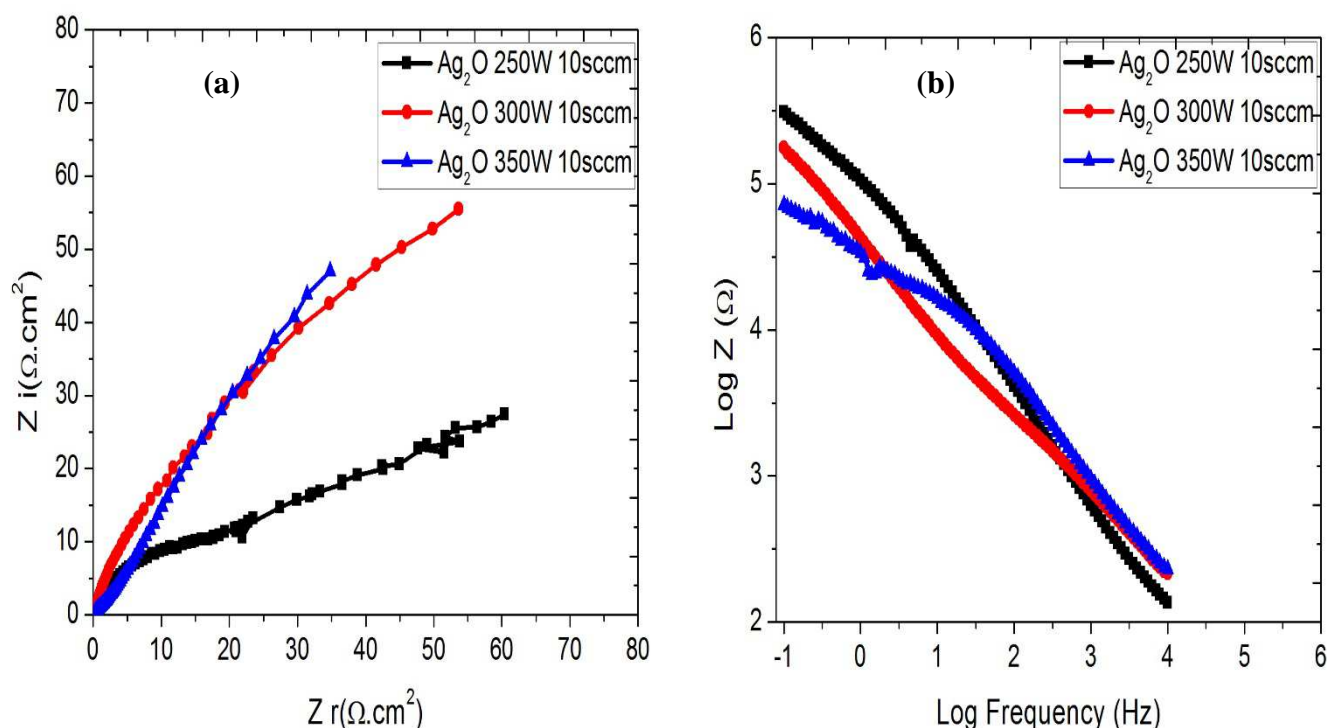


Figure 6: EIS of Ag₂O thin films using (a) Nyquist and (b) Bode plot

3.5 Charge-discharge

Figure 7 shows the charge-discharge curves of silver oxide thin films deposited at a constant oxygen flow rate of 10 sccm and varying power of 250W, 300W and 350W. The mirror-like charge-discharge curves confirm the pseudocapacitance property of silver oxide due to Faradaic redox reaction. Silver oxide thin film deposited at 350W 10 sccm shows a better voltage window utilization, an indication of its potential to store more charge compared to Ag₂O 250W 10 sccm and Ag₂O 300W 10 sccm respectively. This actually stems from Ag₂O 350W 10 sccm morphology offering more surface area and pore for interfacial faradaic reaction and charge storage [64]. The bigger surface area and pore size of Ag₂O 350W 10 sccm pave the way for more electrolyte intrusion, spreading and an improved electrode/electrolyte interaction. This further allows more charge transfer process across the sputtered Ag₂O 350W 10 sccm electrode, thereby encouraging redox reaction process. Furthermore, the stability of the prepared silver oxide thin films was tested for 10000 cycles, at 10mA applied current, for voltage window of 1V. Figure 7 (a, b and c) show the initial and last ten cycles charge-discharge measurements for the three-silver oxide thin film electrodes, with a 2% drop between the initial and the last 10 cycles potential for the entire 10000 cycles.

An indication of the excellent stability of the three silver oxide electrodes for supercapacitor application and an improvement to what has been reported in the literature on the voltage window drop [28].

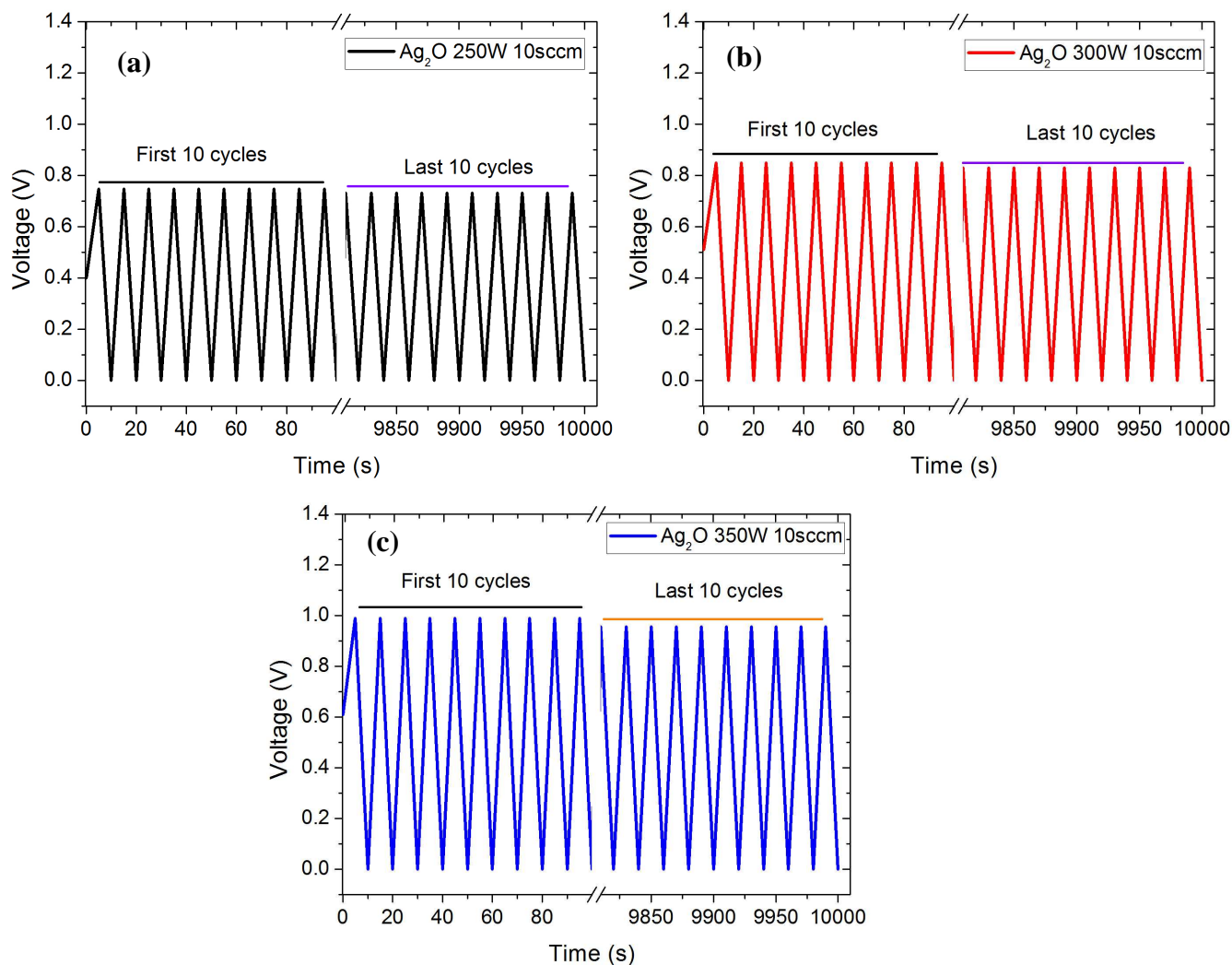


Figure 7: silver oxide thin films first and last 10 cycles charge discharge for 10000 cycles at (a) 250W (b) 300W (c) 350W 10sccm respectively

3.6 Cyclic Voltammetry

Figure 8 shows the cyclic voltammetry of silver oxide thin films in 1-Ethyl-3-methylimidazolium bis(trifluoromethylsulfonyl)imide ionic solution with two redox peaks. The anodic and cathodic peaks are due to the oxidation and reduction of silver oxide thin films by the $[\text{N}(\text{Tf})_2]^-$ anion and $[\text{EMIM}]^+$ cation of the ionic liquid (1-Ethyl-3-methylimidazolium bis(trifluoromethylsulfonyl)imide [77-78]. There is an increase in CV curves of silver oxide thin films sputtered at 350W 10sccm as deposition power increases,

with redox peak voltages at -0.6 to -0.8V and at +0.6 to 0.8V, an indication of charge transfer process taking place. Abedin et al. [79], attributes this increase in peak current to the oxidation of the [EMIM]⁺ cation, a reduction reaction product. These redox peak voltages are within the standard oxidation-reduction potential reported by Amor et al. [80] on silver oxide redox peak. Nanostructure silver oxide film prepared at 350W 10sccm has higher peak current density compared to silver oxide thin films sputtered at 250W 10sccm and 300W 10sccm as shown in Figure 8. This is because at 350W 10sccm, the deposited silver oxide electrode offers more surface area for electrolyte/electrode interaction, resulting in better capacitance performance. Using equation 1, the specific capacitance of the various prepared Ag₂O can be determined [81],

$$C_s = \frac{1}{m \nu (V_c - V_a)} \int_{V_a}^{V_c} I(V) dV \quad (1)$$

Where ν is the potential scan rate (mV/s), $(V_c - V_a)$ is the potential range, I stands for the current response and m the weight of the electrode. Using equation 1, specific capacitance of Ag₂O at 250W 10sccm at 2mV/s, 5mV/s and 10mV/s are 617 F/g, 519 F/g and 429 F/g respectively. At a scan rate of 2mV/s, 5mV/s and 10mV/s, silver oxide thin films sputtered at 300W 10sccm gave specific capacitance of 623 F/g, 540 F/g and 489 F/g respectively. Furthermore, cyclic voltammetry analysis of silver oxide thin films prepared at 350W 10sccm, resulted in specific capacitance of 650 F/g, 591 F/g and 531 F/g, at a scan rate of 2mV/s, 5mV/s and 10mV/s respectively. It is obvious from the specific capacitance calculation that the scan rate affects the oxidation/ reduction peak current height and the shape of the curve, with a scan rate of 10mV/s offering more peak current but less capacitance. This is because a limited number of ions are allowed to diffuse into the microstructure of the silver oxide thin films at a higher scan rate (10mV/s), reducing the redox reaction process [80]. The pseudocapacitance behaviour is revealed on the cathodic and anodic sides of the CV curves, by the peak current at each of voltage level. An indication of valuable utilization of the silver oxide material by the ions from the electrolyte via the redox reaction process. Ag₂O thin film prepared at 350W 10sccm yields higher specific capacitance compared to silver oxide thin films at 250W 10sccm and 300W 10sccm

respectively. The produced Ag_2O 350W 10sccm higher specific capacitance can be attributed to its better morphological arrangement, bigger surface area, pore size and reduced charge transfer resistance as depicted in the SEM, BET and EIS results. The reported specific capacitance in this research is an improvement to 275.50 F/g and 530 F/g reported by oje et al. and Elaiyappillai et al. [28, 82], on silver oxide-based supercapacitors. The measured specific capacitance from cyclic voltammetry analysis for silver oxide thin films still depends on the electrode processing method, surface area, pore size and ion size [28, 82-84].

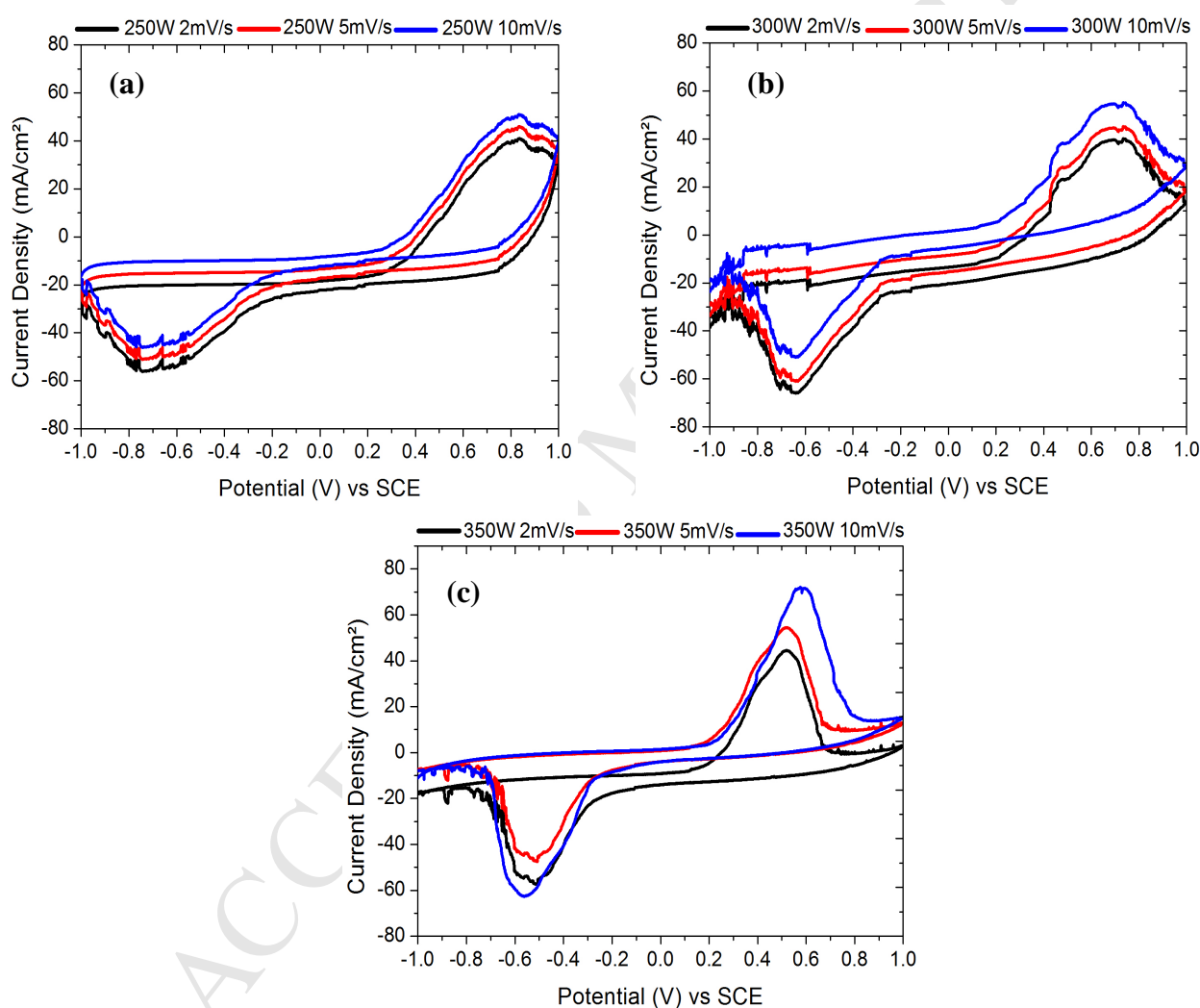


Figure 8: silver oxide thin films CV in ionic solution at 10sccm (a) 250W (b) 300W (c) 350W at scan rate of (2mV/s, 5mV/s, 10mV/s)

Conclusions

In this research, radio frequency magnetron sputtering was successfully used to fabricate thin film electrodes based on nanostructure silver oxide materials, for energy storage application, supercapacitor to be precise. XRD, Raman spectroscopy, XPS and FTIR reveals that the oxide phases belong to silver oxide. The scanning electron micrograph indicates that the deposited silver oxide thin films exhibited Volmer-Weber mechanism growth mode, with film roughness and pores increasing with deposition power. The BET surface area measurement shows that as the deposition power increases the surface area and average pore size, with Ag₂O thin films prepared at 350W exhibiting better wettability, an indication of strong interaction between the electrode/electrolyte.

Furthermore, electrochemical impedance spectroscopy, charge-discharge and cyclic voltammetry in (1-Ethyl-3-methylimidazolium bis(trifluoromethylsulfonyl)imide reveal that Ag₂O thin films produced at 350W, possesses lower charge transfer resistance, good cycle life and a specific capacitance of 650 F/g at 2mV/s scan rate. The enhance specific capacitance at higher deposition power can be linked to silver oxide thin films sputtered at 350W 10sccm offering more surface area, more pore size and reduced charge transfer resistance for oxidation-reduction reaction.

Supercapacitor plays important role in energy storage technology because of the high-power boost it offers as a stand-alone or complementary energy storage device in hybrid cars, trains, space tools, airplanes, windmills, cranes and consumer electronic gadgets. The specific capacitance of 650 F/g offered by silver oxide thin film, demonstrates its electrochemical potential to be used as an active electrode for supercapacitor processing. This is extremely important for energy recovery systems such as car dynamic braking systems, where supercapacitors excellent life cycle, paves the way for it to be used to extend the lifespan of battery storage technology.

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